

POWER SCHOTTKY RECTIFIER

Table 1: Main Product Characteristics

$I_{F(AV)}$	2 x 10 A
V_{RRM}	100 V
T_J	175°C
$V_F(\max)$	0.71 V

FEATURES AND BENEFITS

- High junction temperature capability for converters located in confined environment
- Low leakage current at high temperature
- Low static and dynamic losses as a result of the Schottky barrier
- Avalanche specification

DESCRIPTION

Schottky barrier rectifier designed for high frequency miniature Switched Mode Power Supplies such as adaptors and on board DC/DC converters. Packaged in TO-220AB, I²PAK and TO-220FPAB.

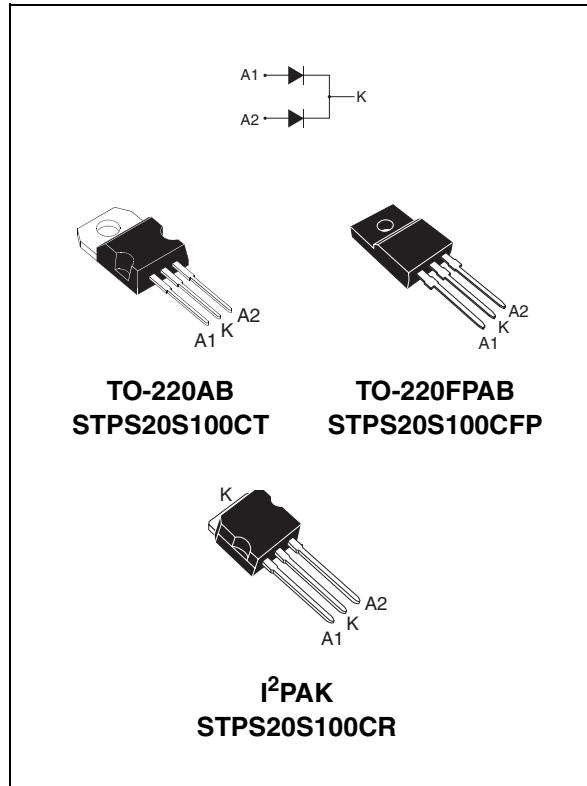


Table 2: Order Codes

Part Numbers	Marking
STPS20S100CT	STPS20S100CT
STPS20S100CFP	STPS20S100CFP
STPS20S100CR	STPS20S100CR

STPS20S100C

Table 3: Absolute Ratings (limiting values, per diode)

Symbol	Parameter				Value	Unit
V _{RRM}	Repetitive peak reverse voltage				100	V
I _{F(RMS)}	RMS forward voltage				30	A
I _{F(AV)}	Average forward current $\delta = 0.5$	TO-220AB / I ² PAK	T _c = 150°C	Per diode	10	A
		TO-220FPAC	T _c = 140°C	Per device	20	
I _{FSM}	Surge non repetitive forward current		t _p = 10ms sinusoidal		180	A
P _{ARM}	Repetitive peak avalanche power		t _p = 1μs T _j = 25°C	7200		W
T _{stg}	Storage temperature range				-65 to + 175	°C
T _j	Maximum operating junction temperature *				175	°C
dV/dt	Critical rate of rise of reverse voltage				10000	V/μs

* : $\frac{dP_{tot}}{dT_j} > \frac{1}{R_{th}(j-a)}$ thermal runaway condition for a diode on its own heatsink

Table 4: Thermal Resistance

Symbol	Parameter			Value	Unit
R _{th(j-c)}	Junction to case	TO-220AB / I ² PAK	Per diode	2.2	°C/W
			Total	1.3	
			Coupling	0.3	
R _{th(c)}	Junction to case	TO-220FPAB	Per diode	4.5	°C/W
			Total	3.5	
			Coupling	2.5	

When the diodes 1 and 2 are used simultaneously:

$$\Delta T_j(\text{diode } 1) = P(\text{diode } 1) \times R_{th(j-c)} (\text{Per diode}) + P(\text{diode } 2) \times R_{th(c)}$$

Table 5: Static Electrical Characteristics (per diode)

Symbol	Parameter	Tests conditions		Min.	Typ	Max.	Unit
I _R *	Reverse leakage current	T _j = 25°C	V _R = V _{RRM}			3.5	μA
		T _j = 125°C			1.3	4.5	mA
V _F **	Forward voltage drop	T _j = 25°C	I _F = 5A			0.73	V
		T _j = 125°C			0.57	0.61	
		T _j = 25°C	I _F = 10A			0.85	
		T _j = 125°C			0.66	0.71	
		T _j = 25°C	I _F = 20A			0.94	
		T _j = 125°C			0.74	0.80	

Pulse test: * tp = 5 ms, δ < 2%

** tp = 380 μs, δ < 2%

To evaluate the conduction losses use the following equation: P = 0.62 × I_{F(AV)} + 0.009 I_F² (RMS)

Figure 1: Average forward power dissipation versus average forward current (per diode)

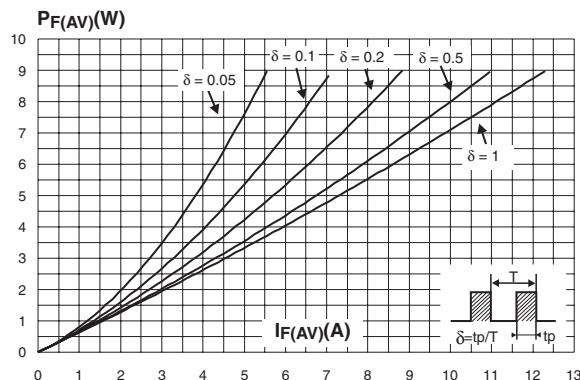


Figure 3: Normalized avalanche power derating versus pulse duration

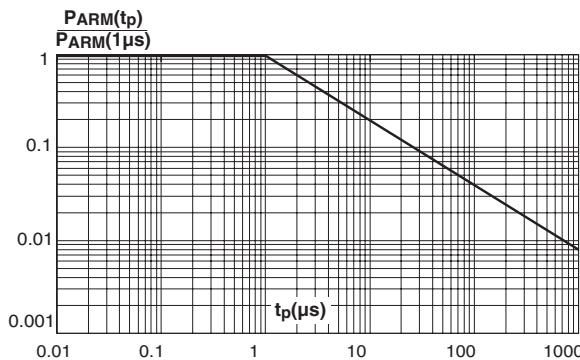


Figure 5: Non repetitive surge peak forward current versus overload duration (maximum values, per diode)

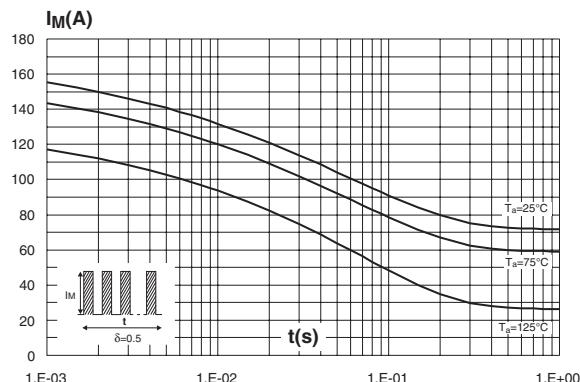


Figure 2: Average forward current versus ambient temperature ($\delta = 0.5$, per diode)

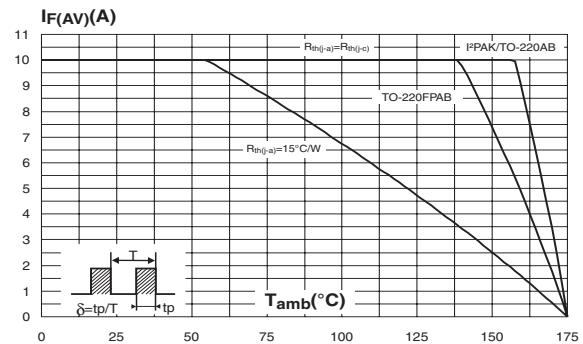


Figure 4: Normalized avalanche power derating versus junction temperature

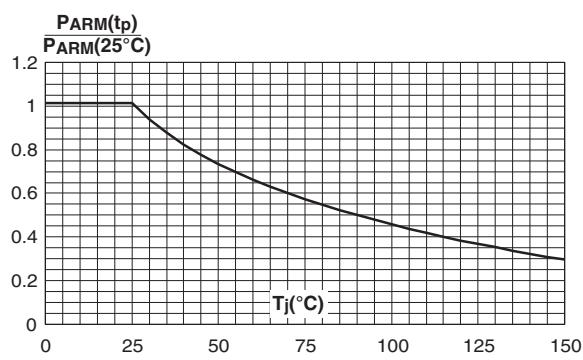
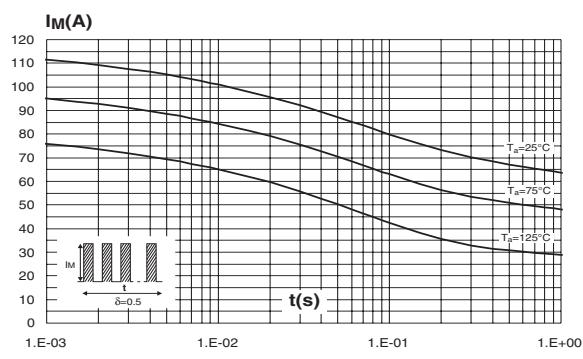


Figure 6: Non repetitive surge peak forward current versus overload duration (maximum values, per diode) (TO-220FPAB)



STPS20S100C

Figure 12: TO-220AB Package Mechanical Data

REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
C	1.23	1.32	0.048	0.051
D	2.40	2.72	0.094	0.107
E	0.49	0.70	0.019	0.027
F	0.61	0.88	0.024	0.034
F1	1.14	1.70	0.044	0.066
F2	1.14	1.70	0.044	0.066
G	4.95	5.15	0.194	0.202
G1	2.40	2.70	0.094	0.106
H2	10	10.40	0.393	0.409
L2	16.4 typ.		0.645 typ.	
L4	13	14	0.511	0.551
L5	2.65	2.95	0.104	0.116
L6	15.25	15.75	0.600	0.620
L7	6.20	6.60	0.244	0.259
L9	3.50	3.93	0.137	0.154
M	2.6 typ.		0.102 typ.	
Diam.	3.75	3.85	0.147	0.151

Table 6: Ordering Information

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STPS20S100CT	STPS20S100CT	TO-220AB	2.20 g	50	Tube
STPS20S100CFP	STPS20S100CFP	TO-220FPAB	2 g	50	Tube
STPS20S100CR	STPS20S100CR	I ² PAK	1.49 g	50	Tube

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.8 m.N.
- Maximum torque value: 1.0 m.N.